## **FORM TWO TERM ONE EXAM 2017**

PHYSICS MARKING SCHEME PAPER 2

## SCHOOLS NET KENYA

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## PHYSICS. PAPER 2 (THEORY) MARKING SCHEME FORM 3

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1.	SECTION A	
	A luminous source of light emits light while a non-luminous source reflects light ✓	
		1mk
2.	Electrons are repelled from the cap and flow to the leaf and plate. ✓ Repulsion between the	
	electrons on the plate and those on the leaf causes the leaf to rise.	
		2mks
3.	13/	
	$\int_{f} Number of waves = \frac{1}{4} - 50 H$	
	$f = \frac{Number of \ waves}{Time \ taken} \checkmark = \frac{1\frac{3}{4}}{35 \times 10^{-3}} = 50H_3 \checkmark$	
	Alt.	2mks
	f = 1 $f = 1$ $f = 1$	ZIIIKS
	$f = \frac{1}{T} = \frac{1}{\sqrt{5 - 5 \times 10^{-3}}} = 50 \text{H}_3 \checkmark$	
4.	Width of the aperture/slit should be approximately or nearly equal to $\lambda$ of the incident wave;	
4.	with of the aperture/shi should be approximately of hearty equal to $\lambda$ of the incident wave;	
		21
		2mks
5.	Slope = $\frac{0.9 - 0.4}{3 - 7} \checkmark = -\frac{1}{f} \checkmark$	
	Slope $=\frac{3-7}{3-7}$	
	· ·	
	$=-\frac{0.5}{5}=0.125$	3mks
	5 - 0.125	
	f = 8cm ✓	
6.	$f = 8cm \checkmark$ $P = \frac{V^2}{R} \checkmark \qquad R = \frac{V^2}{P} = \frac{240^2}{2500}$	
	$P = \frac{\sqrt{R}}{R} \sqrt{R} = \frac{2.18}{R} = \frac{2.18}{2500}$	
	$R = \frac{P}{2500}$	2mks
	= 23.04Ω ✓	
7.		
	<b>▼1</b> ✓	
		1mk
8.	Repulsion only occurs between like poles of magnets while attract also occur between a magnet	
	and a magnetic material	1mk

9.		
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	F-	1 1
		1mk
	·	
	air /	
10	11. d	
10.	Hydrogen gas bubbles form around the positive plate. ✓ The hydrogen gas insulates the positive	2 1
	plate thus increasing internal resistance ✓	2mks
11.	Electrons are attracted towards the rod leaving the atoms at the other end of the ball with net	2mks
	positive charges	
	Trees absorb sound	1mks
12.	In conductor the resistance increases with increase ✓ in temperature while in a semiconductor	
	the resistance reduces with increase in temperature.	1mk
13.	$E = Ir + IR \checkmark$	
	$= 2 \times 0.5 + 2 \times 10$	2mks
	= 11V ✓	
	SECTION B	
14.	(a) (i) The ratio of the sine of angle of incidence to the sine of angle of refraction is a constant	
14.	for a pair of media	1mk
	*	IIIIK
	(ii) – Do not absorb light energy like mirrors	21
	- Not affected by thickness as mirrors	2mks
	- Do not wear off like the peeling of siyvering on mirror.	2 1
	(b) (i) $k^n w = k^n a a^n w$	3mks
	$=$ 1 $\times$ 1.33 $=$ 0.9236	
	1.44	
	(ii) $i = 70^0$	
	$\underline{\text{Sini}} = 0.9236$	
	Sinr	
	$Sin r = \frac{\sin 70^0}{\sin 70^0} = 1.0174$	3mks
	0.9236	
	r is greater than $90^0$ hence the light reflection	
	1 to ground unitary of months and regard to the months and the months are the months and the mon	
	S (***) TIL 1:00	
	(iii) The different colours travel at different velocities hence would have different angles of	
	refraction and are dispersed	1mks
	(iv) The eye would see a spectrum since the light rays are dispersed in the kerosene layer and	
	are internally reflected at the kerosene – water surface the eye would see a spectrum at the	2mks
	surface	
15.	(a) Current flowing through a conductor is directly proportional to the potential difference	1mk
	across it provided the temperature and other physical conditions are kept constant	
	(b) (i) The work done in driving charges through the coil is high due to its resistance. This	
	energy is converted into heat in the coil	2mks
	(ii) $V = IR$ $R = V \checkmark = 12V \checkmark$	
	$\frac{1}{I}$ $\frac{12}{2.4}$	
	$=5.0\Omega$	
	-3.022 (iii) H = VIt	3mks
	$H = 12 \times 2.4 \times 60$	Jiiii
		<u> </u>

	= 1728J	3mks
	(iv) – Using a source with higher emf	
	- Reducing the length of the coil	
	$= P = \frac{V^2}{P}$	2mks
16.	R  (a) capacitance c is the charge stored in a capacitor per unit voltage	1mk
10.	(i) the deflection of the leaf decreases since the pd reduces with the	THIK
	distance of separation, the greater the deflection, the smaller the	2mks
	capacitance.	
	(ii) the deflection of the decreases since the pd increases with the area of	
	overlaps or the greater the deflection the smaller the capacitance.	2mks
	(iii) the deflection of the leaf decreases, the capacitance increases ,since the	
	smaller the deflection the greater the capacitance.	Omileo
	$C_T = C_1 + \frac{C_2 C_3}{C_2 + C_3} \checkmark 1$	2mks
	$C_2+C_3$	
	$=3 \mu F + \frac{4 \times 4}{4 + 4} \checkmark 1$	
	$-3 \mu r + \frac{1}{4+4} $ 1	3mks
	$=3 \mu \text{ F+2 } \mu \text{ F} \checkmark 1$	
	$=5 \mu \text{ f} \checkmark 1$	
	Charge on the 3 $\mu$ F capacitor is the same as the overall charge Q =CV $\checkmark$ 1	
	=5.0×10√1	
	=50C√1	3mks
17.	$(a)(i)T = \frac{T}{20} = \frac{36}{20} = 1.8s$	
	$(a)(t)I = \frac{1}{20} = \frac{1}{20} = 1.88$	2mks
	$(ii) f = \frac{1}{T} = \frac{1}{1.8} = 0.5556 Hz$	3mks
	$(u) f = \frac{1.8}{T} = \frac{0.5556}{1.8} Hz$	SHIKS
	$(c)80cm \Rightarrow S4\lambda$	
	$V = f\lambda$	3mks
	·	
	$=\frac{1}{1.8}\times0.2=0.111m/s$	
	1.8	
18.	a)- A small force (effort) is used to overcome a large force (Load)	
10.	- Less energy is expended in doing work	2mks
	- Less time is used in accomplishing the task	211113
	b) (i) - In one revolution, both wheel and axle complete one circumference	
	- V.R = Effort Distance/Load distance = $2 \prod R/2 \prod r$	3mks
	-V.R = R/r	
	(ii) $V.R = 50/5 = 10$	
	$M.A = efficiency \times V.R/100 = 90 \times 10/100 = 9$	3mks
	Effort = Load/M.A = 200/9 = 22.22N	JIIKS
	c) Gas Pressure = At.Pressure – Pressure due to H <sub>g</sub> Volume	
	$P_{\alpha} = 1.0 \times 10^5 - 0.4 \times 13600 \times 10^5$	
	$P_g = 1.0 \times 10^5 - 0.4 \times 13600 \times 10$ = $94560 \text{N/m}^2$	3mks
	d) By lowering the temperature of the liquid	1mk
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